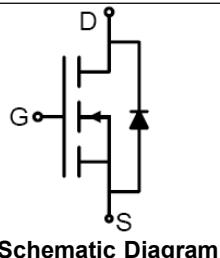


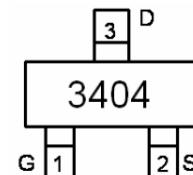
N-Channel Trench Power MOSFET

General Description

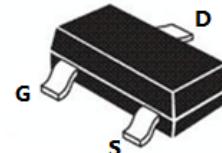
The JY3404X uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a load switch or in PWM applications.



Schematic Diagram



Marking and pin Assignment



SOT-23-3L top view

Features

- $V_{DS} = 30V, ID = 5.8A$
- $R_{DS(ON)} < 30m\Omega @ V_{GS} = 10V$
- $R_{DS(ON)} < 42m\Omega @ V_{GS} = 4.5V$
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- PWM applications
- Load switch
- Power management

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3404	JY3404X	SOT-23-3L	Ø180mm	8mm	3000 units

Table 1. Absolute Maximum Ratings (TA=25°C)

Symbol	Parameter	Value	Unit
V_{DS}	Drain-Source Voltage ($V_{GS}=0V$)	30	V
V_{GS}	Gate-Source Voltage ($V_{DS}=0V$)	± 20	V
I_D	Drain Current-Continuous	5.8	A
I_{DM} (pulse)	Drain Current-Continuous@ Current-Pulsed (Note 1)	30	A
P_D	Maximum Power Dissipation	1.5	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 To 150	°C

Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature

Table 2. Thermal Characteristic

Symbol	Parameter	Value	Unit
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	85	°C/W

Table 3. Electrical Characteristics (TA=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
On/Off States						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V I _D =250μA	30	34		V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =30V, V _{GS} =0V			1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V			±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.2	1.6	2.4	V
g _{FS}	Forward Transconductance	V _{DS} =5V, I _D =5A	3	5.8		S
R _{DS(ON)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =5.8A		21	30	mΩ
		V _{GS} =4.5V, I _D =2.9A		32	42	mΩ
Dynamic Characteristics						
C _{iss}	Input Capacitance	V _{DS} =15V, V _{GS} =0V, f=1.0MHz		560		pF
C _{oss}	Output Capacitance			125		pF
C _{rss}	Reverse Transfer Capacitance			90		pF
Switching Times						
t _{d(on)}	Turn-on Delay Time	V _{DD} =15V, I _D =5.5A, R _L =15Ω V _{GS} =10V, R _G =2.5Ω		10		nS
t _r	Turn-on Rise Time			4		nS
t _{d(off)}	Turn-Off Delay Time			27		nS
t _f	Turn-Off Fall Time			5		nS
Q _g	Total Gate Charge	V _{DS} =10V, I _D =3.6A, V _{GS} =5V		7		nC
Q _{gs}	Gate-Source Charge			1.5		nC
Q _{gd}	Gate-Drain Charge			3		nC
Source-Drain Diode Characteristics						
I _{SD}	Source-Drain Current(Body Diode)				5.8	A
V _{SD}	Forward on Voltage ^(Note 1)	V _{GS} =0V, I _S =1A		0.78	1	V

Notes 1. Repetitive Rating: Pulse width limited by maximum junction temperature.

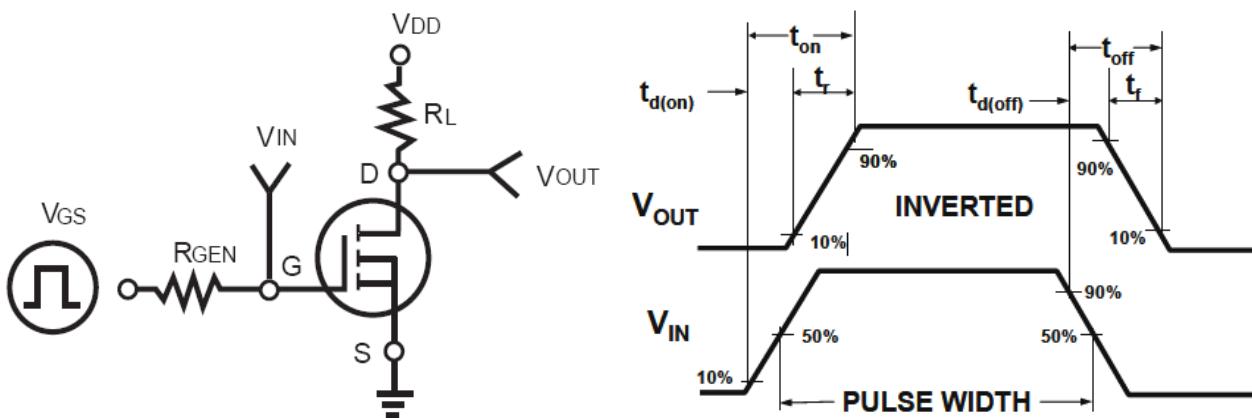
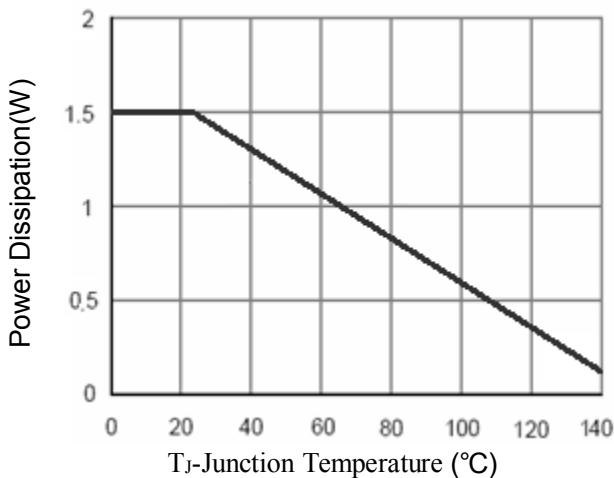
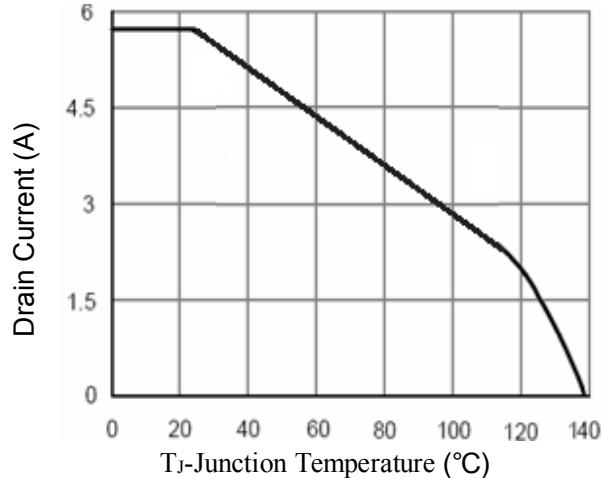
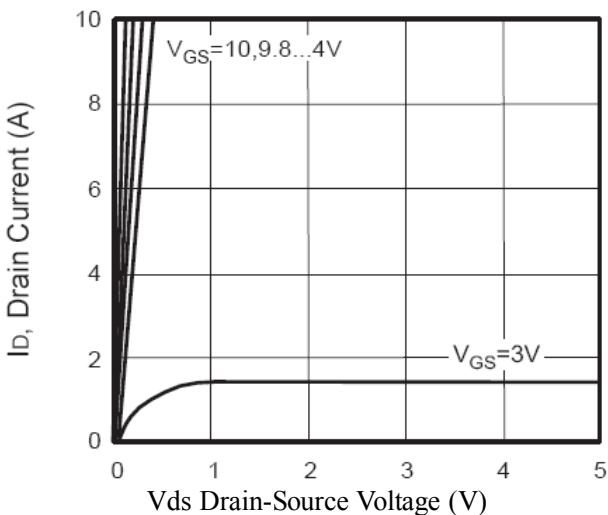
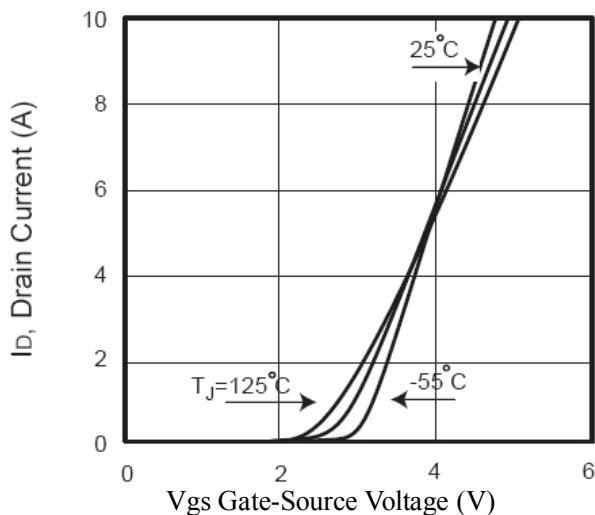
Switch Time Test Circuit and Switching Waveforms:

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (Curves)
Figure1. Power Dissipation

Figure2. Drain Current

Figure3. Output Characteristics

Figure4. Transfer Characteristics


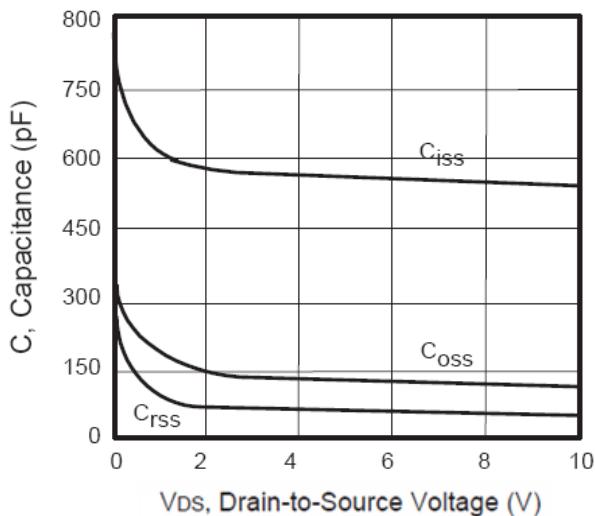
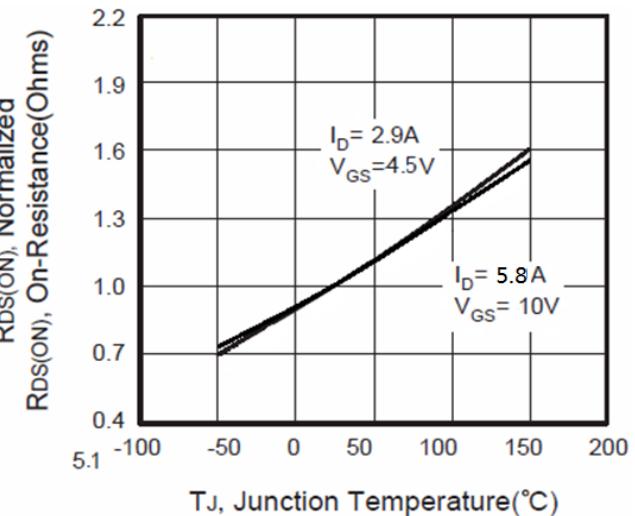
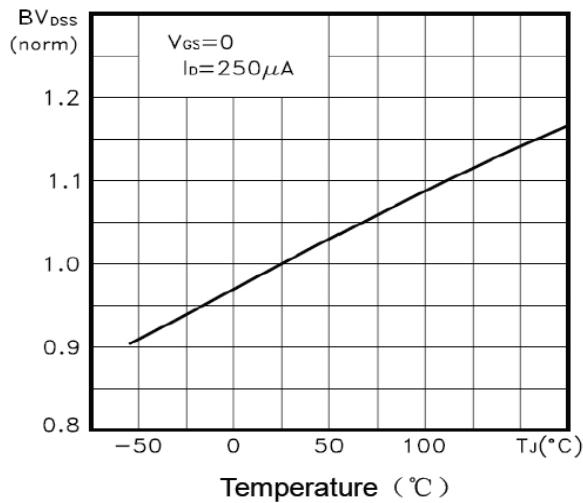
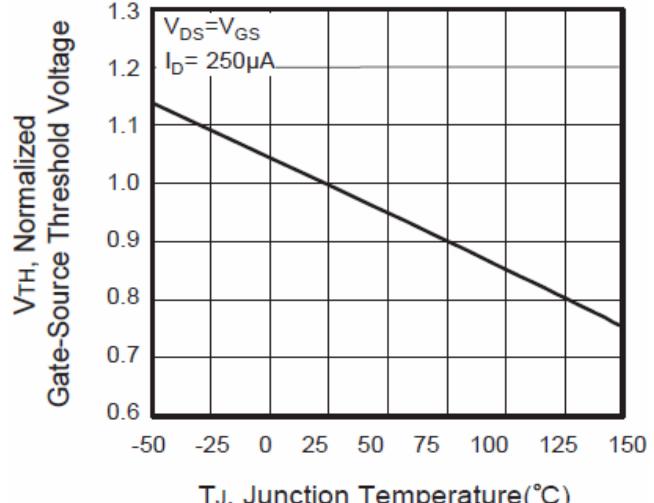
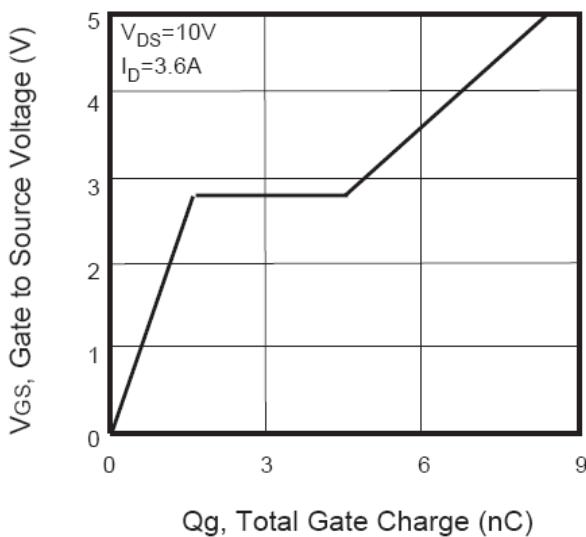
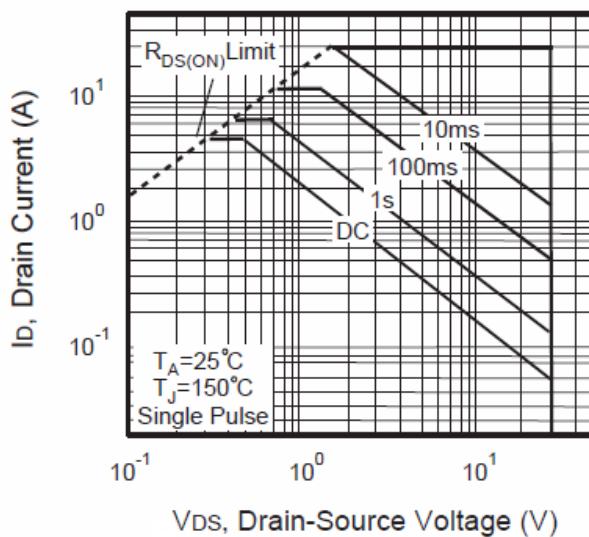
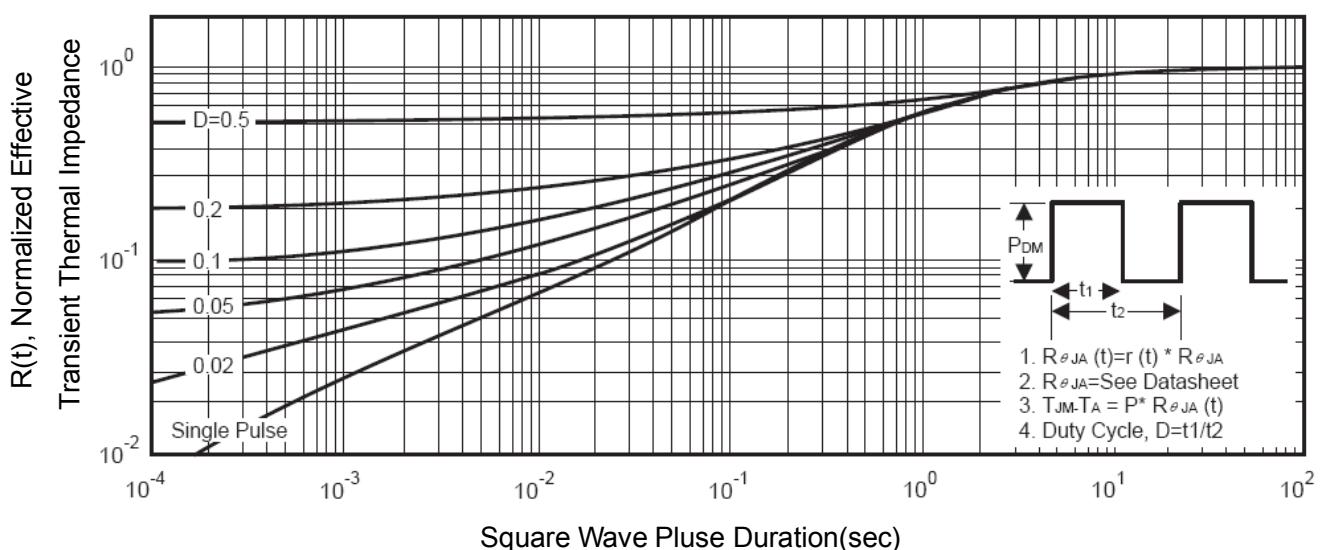
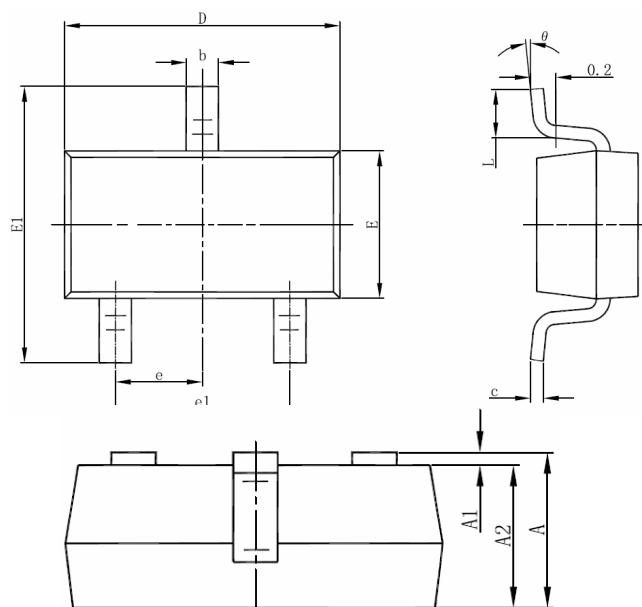
Figure5. Capacitance

Figure6. R_{Ds(ON)} vs Junction Temperature

Figure7. Max BV_{DSS} vs Junction Temperature

Figure8. V_{GS(th)} vs Junction Temperature

Figure9. Gate Charge Waveforms

Figure10. Maximum Safe Operating Area




Figure11. Normalized Maximum Transient Thermal Impedance



SOT-23-3L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

Carrier Dimensions

PKG TYPE	W	P	E	F	D	D1	Po	Po10	P2
SOT-23	8.00	4.00	1.75	3.50	1.50	1.00	4.00	40.00	2.00
Tolerance	+0.3/-0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.2	±0.05

A0	B0	K0	T
3.15	2.77	1.22	0.20
±0.1	±0.1	±0.1	±0.02

